

SEMICONDUCTOR TECHNICAL DATA

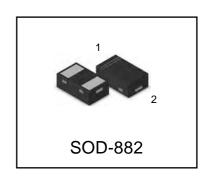
FTV05LLUUL2

ESD Protection Diodes

Discription

The FTV05LLUUL2 is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time, make these parts ideal for ESD protection on designs where board space is at a premium. Because of its small size,

it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space is at a premium.



Applications

- Cellular phones audio
- MP3 players
- Digital cameras
- Portable applicationss
- mobile telephone



Ordering information

Device	Shipping		
FTV05LLUUL2	10000/Tape&Reel		

Features

- Low Leakage
- Response Time is Typically < 1 ns
- ESD Rating of Class 3 (> 16 kV) per Human Body Model
- IEC61000-4-2 Level 4 ESD Protection
- We declare that the material of product compliant with RoHS requirements and Halogen Free.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Air discharge Contact discharge		±15 ±8	kV kV
ESD Voltage Per Human Body Model		16	kV
Total Power Dissipation on FR-5 Board (Note 1)	PD	200	mW
@ T _A =25			
Junction and Storage Temperature Range	TJ,TSTG	-55 to 150	
Lead Solder Temperature – Maximum	TL	260	
(10 Second Duration)			

Stresses exceeding Maximum Ratings may damage the device. Maximum Rating are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. FR-5 = 1.0*0.75*0.62 in.

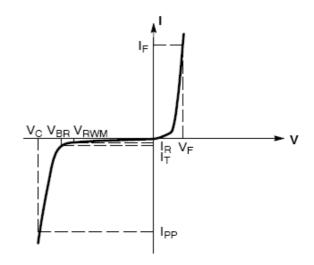


FTV05LLUUL2

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter			
I _{PP}	Maximum Reverse Peak Pulse Current			
V _C Clamping Voltage @ I _{PP}				
V _{RWM} Working Peak Reverse Voltage				
I _R Maximum Reverse Leakage Current @ V _{RWM}				
V _{BR} Breakdown Voltage @ I _T				
Ι _Τ	Test Current			
P _{pk} Peak Power Dissipation				
С	Capacitance @ V _R = 0 and f = 1.0 MHz			



Uni-Directional TVS

ELECTRICAL CHARACTERISTICS

	V _{RWM} (V)	I _R (uA) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)	Ι _Τ	V _C (V) @ I _{PP} = 1 A (Note 3)	V _C (V) @MAX I _{PP} (Note 3)	I _{PP} (A) (Note 3)	P _{PK} (W) (Note 3)	C (p	oF)
Device	Max	Max	Min	mA	Max	Max	Max	Max	Тур	Max
FTV05LLUUL2	5	0.5	6	1.0	12	20	4	60	0.5	0.6

Other voltage available upon request.

- 2. V_{BR} is measured with a pulse test current IT at an ambient temperature of 25°C.
- 3. Surge current waveform per Figure 1.

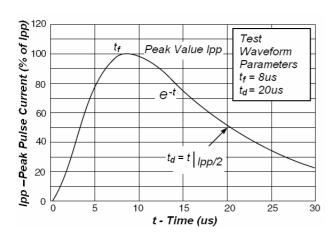


Fig1. Pulse Waveform

Revision No: 0

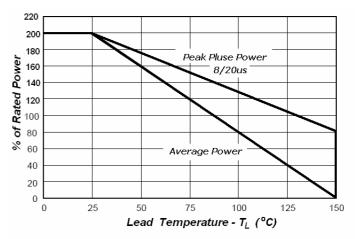


Fig2.Power Derating Curve



FTV05LLUUL2

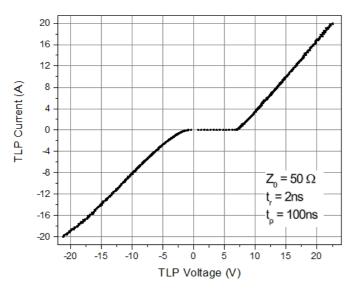


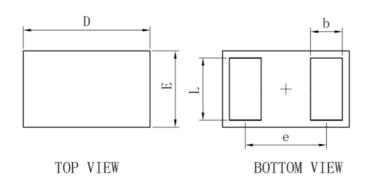
Fig3.TLP Measurement



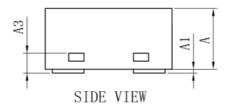
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OUTLINE AND DIMENSIONS

SOD-882

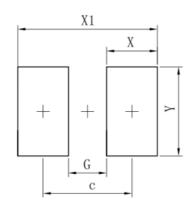


SOD-882				
Dim	Min	Тур	Max	
D	0.95	1.00	1.05	
Е	0.55	0.60	0.65	
е	-	0.64	-	
L	0.44	0.49	0.54	
b	0.20	0. 25	0.30	
A	0.43	0.48	0.53	
A1	0	_	0.05	
А3	0. 127REF.			
All Dimensions in mm				



SOLDERING FOOTPRINT

SOD-882



Dimensions	(mm)
С	0.70
G	0.30
X	0.40
X1	1.10
Y	0. 70